



1.8 nV/ $\sqrt{\text{Hz}}$, 36 V Precision Single and Dual Amplifier

Preliminary Technical Data

ADA4004-1 and ADA4004-2

FEATURES

- Very low voltage noise: 1.8 nV/ $\sqrt{\text{Hz}}$
- Low input bias current: 100 nA maximum
- Offset voltage: 100 μV maximum
- High gain: 120 dB
- Wide bandwidth: 12 MHz
- $\pm 5\text{ V}$ to $\pm 15\text{ V}$ operation

APPLICATIONS

- Precision instrumentation
- Filter blocks
- Microphone preamplifier
- Industrial control
- Thermocouples and RTDs
- Reference buffers

GENERAL DESCRIPTION

The ADA4004-1 and ADA4004-2 are single and dual precision bipolar op amps that featuring a 1.8 nV/ $\sqrt{\text{Hz}}$ precision, 40 μV offset, 0.7 $\mu\text{V}/^\circ\text{C}$ drift, 12 MHz bandwidth, and low 1.7 mA/amplifier supply current.

The ADA4004 is designed on the high performance *iPolar*[™] process, enabling improvements such as reduced noise and power consumption, increased speed and stability, and a smaller footprint size. Novel design techniques enable the ADA4004 to achieve 1.8 nV/ $\sqrt{\text{Hz}}$ voltage noise density and a low 6 Hz 1/f noise corner frequency while consuming just 1.7 mA/amplifier. The small package saves board space, reduces cost, and improves layout flexibility.

Applications for these amplifiers include high precision controls, PLL filters, high performance precision filters, medical and analytical instrumentation, precision power supply controls, ATE, and data acquisition systems.

The high performance ADA4004 is offered in the very small 5-lead SOT and 8-lead SOIC for the single (ADA4004-1) and the 8-lead MSOP and 8-lead SOIC for the dual (ADA4004-2), lead-free surface-mount packages. Operation is fully specified from $\pm 5\text{ V}$ to $\pm 15\text{ V}$ from -40°C to $+125^\circ\text{C}$.

PIN CONFIGURATIONS

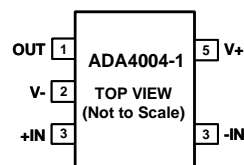


Figure 1. 5-Lead SOT (RJ-5)

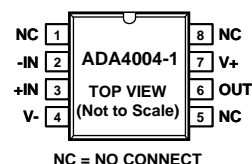


Figure 2. 8-Lead SOIC (R-8)

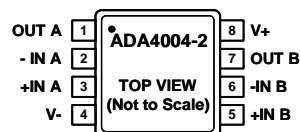


Figure 3. 8-Lead MSOP (RM-8) and 8-Lead SOIC (R-8)

Rev. PrB

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SPECIFICATIONS

$V_S = \pm 5.0\text{ V}$, $V_{CM} = 0\text{ V}$, $T_A = +25^\circ\text{C}$, unless otherwise specified.

Table 1.

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|-------------------------------|--------------------------|--|------|----------|------|------------------------------|
| INPUT CHARACTERISTICS | | | | | | |
| Offset Voltage | V_{OS} | $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | | 40 | 140 | μV |
| Input Bias Current | I_B | $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | | 40 | 85 | nA |
| Input Offset Current | I_{OS} | $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | | 40 | 85 | nA |
| Input Voltage Range | | $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | -3.5 | | +3.5 | V |
| Common-Mode Rejection Ratio | CMRR | $V_{CM} = -3.0\text{ V to } +3.0\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | 105 | 111 | | dB |
| Open-Loop Gain | A_{VO} | $R_L = 2\text{ k}\Omega$, $V_O = -2.5\text{ V to } +2.5\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | 250 | 400 | | V/mV |
| Offset Voltage Drift | $\Delta V_{OS}/\Delta T$ | $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | | 0.7 | 1 | $\mu\text{V}/^\circ\text{C}$ |
| OUTPUT CHARACTERISTICS | | | | | | |
| Output Voltage High | V_{OH} | $R_L = 2\text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | 3.7 | 3.9 | | V |
| Output Voltage Low | V_{OL} | $R_L = 2\text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | 3.4 | 3.6 | | V |
| Short Circuit Limit | I_{SC} | $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | | 25 | -3.6 | mA |
| Output Current | I_O | $V_{OUT} = \pm 3.6\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | | ± 10 | -3.5 | mA |
| POWER SUPPLY | | | | | | |
| Power Supply Rejection Ratio | PSRR | $V_S = \pm 5.0\text{ V to } \pm 15.0\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | 110 | 118 | | dB |
| Supply Current/Amplifier | I_{SY} | $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | 110 | | 1.7 | mA |
| | | | | | 2.0 | mA |
| DYNAMIC PERFORMANCE | | | | | | |
| Slew Rate | SR | $R_L = 2\text{ k}\Omega$ to ground | | 2.7 | | V/ μs |
| Gain Bandwidth Product | GBP | | | 12 | | MHz |
| NOISE PERFORMANCE | | | | | | |
| Voltage Noise | $e_{n\text{ p-p}}$ | 0.1 Hz to 10 Hz | | 0.1 | | $\mu\text{V p-p}$ |
| Voltage Noise Density | e_n | $f = 1\text{ kHz}$ | | 1.8 | | nV/ $\sqrt{\text{Hz}}$ |
| Current Noise Density | i_n | $f = 10\text{ Hz}$ | | 3.5 | | pA/ $\sqrt{\text{Hz}}$ |
| Current Noise Density | i_n | $f = 200\text{ Hz}$ | | 1.2 | | pA/ $\sqrt{\text{Hz}}$ |

$V_S = \pm 15\text{ V}$, $V_{CM} = 0\text{ V}$, $T_A = +25^\circ\text{C}$, unless otherwise specified.

Table 2.

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|-------------------------------|--------------------------|---|-------|----------|--------|------------------------|
| INPUT CHARACTERISTICS | | | | | | |
| Offset Voltage | V_{OS} | $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | | 40 | 125 | μV |
| | | | | | 270 | μV |
| Input Bias Current | I_B | $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | | 40 | 90 | nA |
| | | | | | 165 | nA |
| Input Offset Current | I_{OS} | $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | | | 60 | nA |
| | | | | | 100 | nA |
| Input Voltage Range | | | -12.5 | | +12.5 | V |
| Common-Mode Rejection Ratio | CMRR | $V_{CM} = -12.5\text{ V to }+12.5\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | 110 | 113 | | dB |
| Open-Loop Gain | A_{VO} | $R_L = 2\text{ k}\Omega$, $V_O = -12.5\text{ V to }+12.5\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | 100 | 104 | | dB |
| | | | 500 | 1200 | | V/mV |
| Offset Voltage Drift | $\Delta V_{OS}/\Delta T$ | $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | 250 | 500 | | V/mV |
| | | | | 0.7 | 1 | μV |
| OUTPUT CHARACTERISTICS | | | | | | |
| Output Voltage High | V_{OH} | $R_L = 2\text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | 13.4 | 13.6 | | V |
| | | | 13.1 | 13.3 | | V |
| Output Voltage Low | V_{OL} | $R_L = 2\text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | | -13.3 | -13.2 | V |
| | | | | -13.25 | -13.18 | V |
| Short Circuit Limit | I_{SC} | | | 25 | | mA |
| Output Current | I_O | $V_{OUT} = \pm 13.6\text{ V}$ | | ± 10 | | mA |
| POWER SUPPLY | | | | | | |
| Power Supply Rejection Ratio | PSRR | $V_S = \pm 5.0\text{ V to } \pm 15.0\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | 110 | 118 | | dB |
| | | | 110 | | | dB |
| Supply Current/Amplifier | I_{SY} | $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | | | 1.775 | mA |
| | | | | | 2.10 | mA |
| DYNAMIC PERFORMANCE | | | | | | |
| Slew Rate | SR | $R_L = 2\text{ k}\Omega$ to ground | | 2.7 | | V/ μs |
| Gain Bandwidth Product | GBP | | | 12 | | MHz |
| NOISE PERFORMANCE | | | | | | |
| Voltage Noise | $e_{n\text{ p-p}}$ | 0.1 Hz to 10 Hz | | 0.15 | | $\mu\text{V p-p}$ |
| Voltage Noise Density | e_n | $f = 1\text{ kHz}$ | | 1.8 | | nV/ $\sqrt{\text{Hz}}$ |
| Current Noise Density | i_n | $f = 10\text{ Hz}$ | | 3.5 | | pA/ $\sqrt{\text{Hz}}$ |
| Current Noise Density | \dot{i}_n | $f = 200\text{ Hz}$ | | 1.2 | | pA/ $\sqrt{\text{Hz}}$ |

ABSOLUTE MAXIMUM RATINGS

Table 3.

| Parameter | Rating |
|--------------------------------------|---|
| Supply Voltage | $\pm 18\text{ V}/+36\text{ V}$ |
| Input Voltage | $\pm V$ supply |
| Differential Input Voltage | $\pm V$ supply |
| Output Short-Circuit Duration to GND | Indefinite |
| Storage Temperature Range | -65°C to $+150^{\circ}\text{C}$ |
| Operating Temperature Range | -40°C to $+125^{\circ}\text{C}$ |
| Junction Temperature Range | -65°C to $+150^{\circ}\text{C}$ |
| Lead Temperature (Soldering 60 sec) | 300°C |

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.